NPN Epitaxial Planar Silicon Transistor

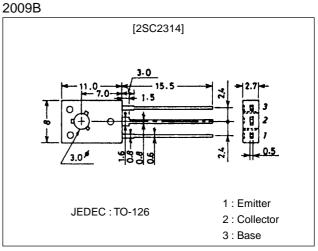


2SC2314

27MHz CB Transceiver Driver Applications

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}	R _{BE} =150Ω	75	V
Collector-to-Emitter Voltage	VCER		75	V
Collector-to-Emitter Voltage	VCEO		45	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	۱ _C		1.0	A
Collector Current (Pulse)	ICP		1.5	A
Collector Dissipation	PC		750	mW
		Tc=25°C	5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		–55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0			1.0	μA
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			1.0	μA
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =10μA, I _E =0	75			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CER	$I_{C}=1mA, R_{BE}=150\Omega$	75			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	45			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =10μA, I _C =0	5			V
* • The 2SC2314 are classified by 500mA her	as follows ·	60 D 120 100 E 200 160 E 320				

* : The 2SC2314 are classified by 500mA h_{FE} as follows : 60 D 120 100 E 200 160 F 320

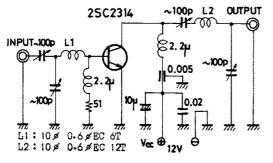
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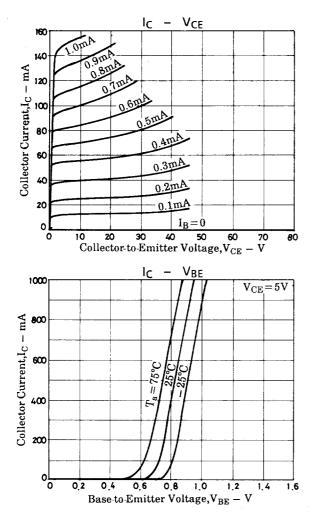
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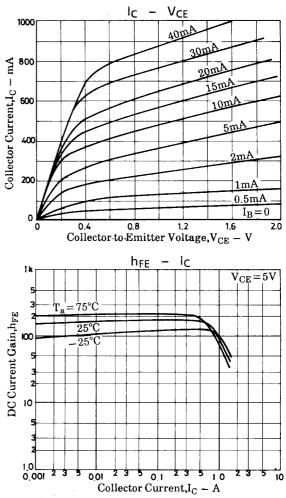
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
DC Current Gain	hFE	V _{CE} =5V, I _C =500mA	60*		320*	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =50mA	180	250		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		15	25	pF
Output Power	PO	V _{CC} =12V, f=27MHz, Pi=35mW	1.0	1.8		W
Collector Efficiency	ης	See specified test circuit.	60			%
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =500mA, I _B =50mA		0.2	0.6	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =500mA, I _B =50mA		0.9	1.2	V

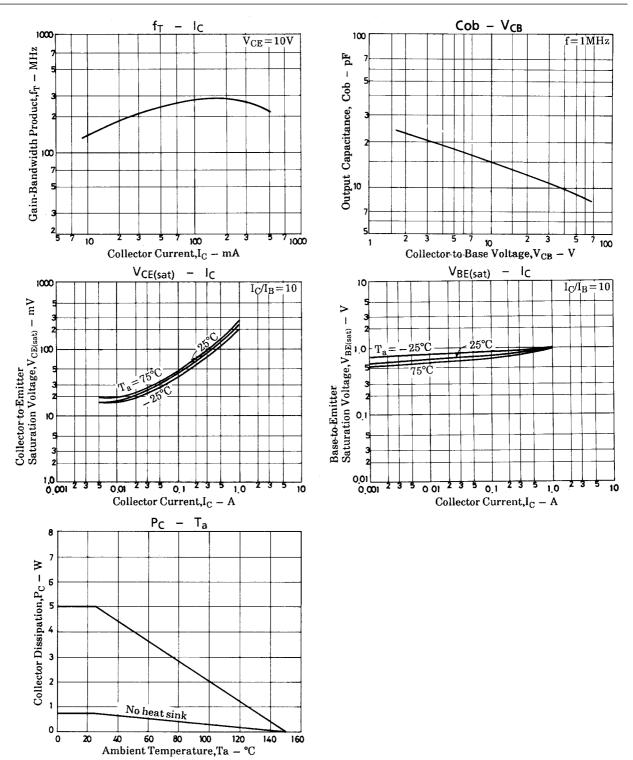
Collector Efficiency Test Circuit



Unit (resistance : Ω , capacitance : F)







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